

HIGH VOLTAGE POWER SCHOTTKY RECTIFIER

Product Summary

V _{RRM} (V)	I _O (A)	V _{F (MAX)} (V) @ +25°C	I _{R (MAX)} (mA) @ +25°C
100	2x15	0.8	0.045

Description

High voltage dual Schottky rectifier suited for switch mode power supplies and other power converters. This device is intended for use in medium voltage operation, and particularly, in high frequency circuits where low switching losses and low noise are required.

MBR30H100C is available in TO-220-3 (2) and TO-220F-3 (Option 1) packages.

Applications

- Power Supply Output Rectification
- Power Management
- Instrumentation



TO-220F-3 (Option 1)

Features

- Low Forward Voltage: 0.8V @ +25°C
- High Surge Current Capacity
- +175°C Operating Junction Temperature
- 30A Total (15A Each Diode Leg)
- · Guard-Ring for Stress Protection
- Pb-free Package
- TO-220-3 (2) and TO-220F-3 (Option 1)
 - Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Available in "Green" Packages: TO-220-3 (2) and TO-220F-3 (Option 1)
 - Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
 - Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

- Case: TO-220-3 (2), TO-220F-3 (Option 1)
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 (3)
- · Polarity: See Below
- Weight:
 - TO-220-3 (2) 1.95 Grams (Approximate)
 - TO-220F-3 (Option 1) 1.69 Grams (Approximate)



TO-220-3 (2)

Notes:

1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.

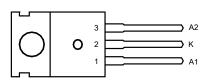
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- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

A1

Pin Assignments

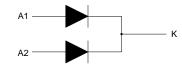


TO-220-3 (2)

Document number: DS36965 Rev. 3 - 2

(Front View)

TO-220F-3 (Option 1)



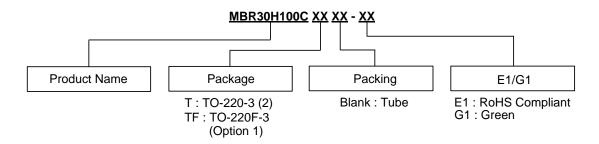
Internal Structure of MBR30H100C

(Front View)

3 2



Ordering Information (Note 4)



Note 4: Diodes IC's Pb-free products, as designated with "E1" suffix in the part number, are RoHS compliant. Products with "G1" suffix are available in green packages.

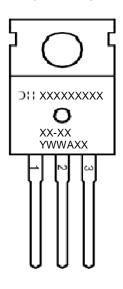


Package	Part Number	Marking ID	Packing
TO-220-3 (2)	MBR30H100CT-E1	MBR30H100CT-E1	50 Pieces/Tube
TO-220-3 (2)	MBR30H100CT-G1	MBR30H100CT-G1	50 Pieces/Tube
TO-220F-3 (Option 1)	MBR30H100CTF-E1	MBR30H100CTF-E1	50 Pieces/Tube
TO-220F-3 (Option 1)	MBR30H100CTF-G1	MBR30H100CTF-G1	50 Pieces/Tube

Marking Information

(1) TO-220-3 (2)





First and Second Lines: Logo and Marking ID

(See Ordering Information)
Third Line: Date Code

Y: Year

WW: Work Week of Molding A: Assembly House Code

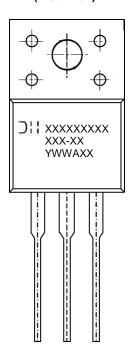
XX: 7th and 8th Digits of Batch Number



Marking Information (Cont.)

(2) TO-220F-3 (Option 1)

(Front View)



First and Second Lines: Logo and Marking ID

(See Ordering Information)
Third Line: Date Code

Y: Year

WW: Work Week of Molding A: Assembly House Code

XX: 7th and 8th Digits of Batch Number

Maximum Ratings (Each Diode Leg) (Note 5)

Characteristic	Symbol	Rating	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	100	٧
Average Rectified Forward Current (Rated V _R) T _C = +162°C	I _{F(AV)}	15	А
Peak Repetitive Forward Current (Rated V _R , Square Wave, 20kHz) T _C = +150°C	I _{FRM}	30	А
Non Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Half Wave, Single Phase, 60Hz)	I _{FSM}	250	А
Operating Junction Temperature (Note 6)	TJ	+175	°C
Storage Temperature Range	T _{STG}	-65 to +175	°C
Voltage Rate of Change (Rated V _R)	dv/dt	10000	V/µs
ESD (Machine Model = C)	_	>400	V
ESD (Human Body Model = 3B)	-	>8000	V

Notes: 5. Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

6. The heat generated must be less than the thermal conductivity from Junction to Ambient: $dP_D/dT_J < 1/\theta_{JA}$.



Thermal Characteristics

Characteristic	Symbol	Rating		Unit	
Maximum Thermal Resistance (Junction to Case)	Rθ _{JC}	TO-220-3 (2)	2.0	0.000	
(Note 7)		TO-220F-3 (Option 1)	2.5	°C/W	
Maximum Thermal Resistance (Junction to Ambient) (Note 7)	Rθ _{JA}	TO-220-3 (2)	60	°C/W	

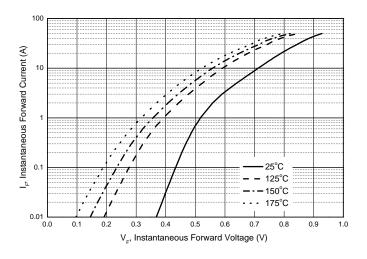
Note 7: Device mounted on heat sink, with minimum recommended pad layout per http://www.diodes.com

Electrical Characteristics (Each Diode Leg)

Characteristic	Symbol	Rating	Unit	Test Condition
) V _F	0.80	V	I _F = 15A, T _C = +25°C
		0.67		I _F = 15A, T _C = +125°C
Maximum Instantaneous Forward Voltage Drop (Note 8)		0.93		I _F = 30A, T _C = +25°C
		0.80		I _F = 30A, T _C = +125°C
Maximum Instantaneous Reverse Current (Note 8)	I _R	6.0	mA	Rated DC Voltage, T _C = +125°C
		0.0045		Rated DC Voltage, T _C = +25°C

Note 8: Short duration pulse test used to minimize self-heating effect, Pulse Test Width = $300\mu s$, Duty Cycle $\leq 2.0\%$.





0.01

1E-3

1E-4

1E-5

1E-6

1E-7

1E-8

1E-9

20

40

60

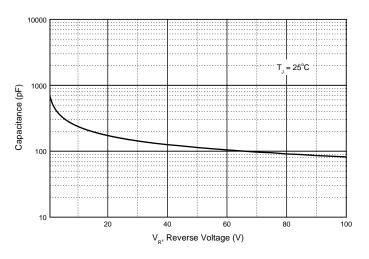
80

100

V_p, Reverse Voltage (V)

Figure 1. Typical Forward Voltage

Figure 2. Typical Reverse Current



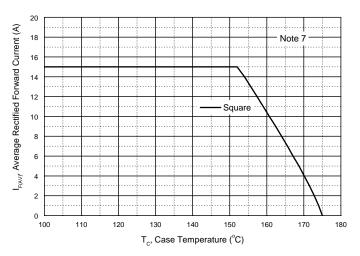


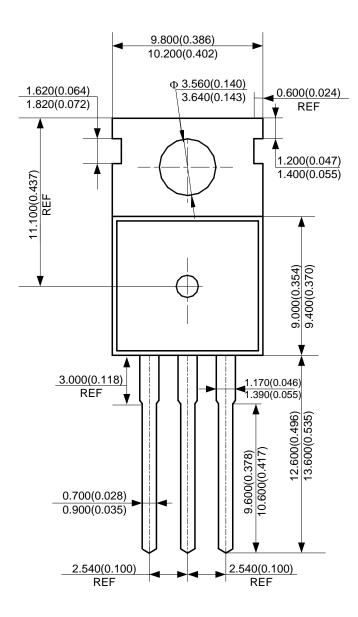
Figure 3. Capacitance vs. V_R, Reverse Voltage

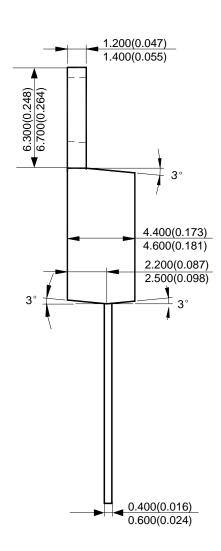
Figure 4. Average Rectified Forward Current vs. Case Temperature (Square, Each Diode)



Package Outline Dimensions (All dimensions in mm(inch).)

(1) Package Type: TO-220-3 (2)

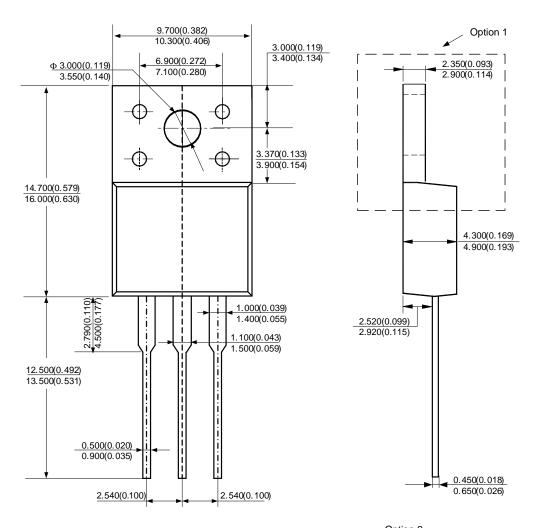


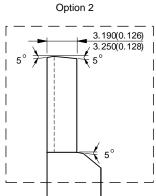




Package Outline Dimensions (Cont. All dimensions in mm(inch).)

(2) Package Type: TO-220F-3







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